

FYSC23

---

# Semiconductor lab

---

*Author*

Fredrik Bergelv

`fredrik.bergelv@live.se`



LUND UNIVERSITY

February 20, 2025

## Abstract

# Contents

<b>1</b>	<b>Introduction</b>	<b>1</b>
<b>2</b>	<b>Theory</b>	<b>1</b>
2.1	Bandgap . . . . .	1
2.2	Semiconductors . . . . .	1
2.3	Doping . . . . .	2
2.4	Pn-junction . . . . .	2
2.5	LED . . . . .	2
<b>3</b>	<b>Experiment</b>	<b>2</b>
<b>4</b>	<b>Result</b>	<b>3</b>
4.1	Part 1 . . . . .	3
4.2	Part 2 . . . . .	4
4.3	Part 3 . . . . .	4
<b>5</b>	<b>Discussion</b>	<b>5</b>
<b>6</b>	<b>Conclusion</b>	<b>5</b>

# 1 Introduction

Semiconductors are becoming more and more important for our society. One important application of semiconductors is light emitting diodes (LEDs) [1] which are used in e.g. displays and lighting, but also have application in medicine. LEDs also show a much better efficiency than earlier lightbulbs, thus decreasing energy consumption [1], something which is becoming increasingly more important. The basic part of the LED, the pn-junction, is also used in solar cells and can be used to produce energy from light [1].

## 2 Theory

### 2.1 Bandgap

The bands in solid state materials are energy continuum that arises in solid state materials due to the number of atoms close to each other [1]. The valance band is the highest band under the Fermi energy and where the electrons are bound to the atoms. The conduction band is the lowest band above the Fermi energy, and where electrons can move freely [1]. The bandgap is the energy difference between the valance band and the conduction band and can be used to describe different materials. For conductors the bandgap is zero and electrons are free to move, for insulators the bandgap is large and a lot of energy is needed to excite an electron from the valance band to the conduction band, and for semiconductors the bandgap exist but is smaller than for insulators [1]. The definition of the size of the bandgap for insulators and semiconductors is a bit arbitrary, but is usually said to be around 3 eV [1].

### 2.2 Semiconductors

Semiconductors, as stated in the previous section, have a bandgap under 3 eV but above 0 eV. This is a bandgap which can quite easily be excited and opens up for many applications [1]. One example is exciting the bandgap using light from the sun to produce energy. Applying a voltage to a semiconductor can also excite the bandgap. If an electron is excited from the valance band to the conduction band, a hole is left in the valance band which behave as a positive charge [1]. An excited electron will thermalize in the conduction band and lose energy to phonons and then eventually recombine with a hole in the valance band [1].

## 2.3 Doping

## 2.4 Pn-junction

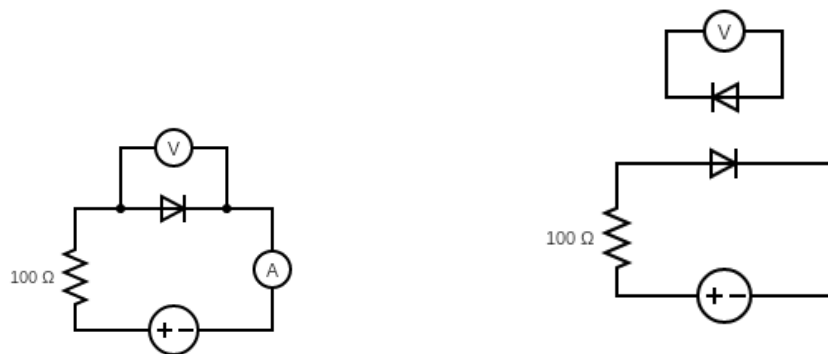
## 2.5 LED

# 3 Experiment

During the first part of the lab, we measured the intensity of a white diode at different voltages. The white diode was a violet diode, covered in a phosphorus layer that emitted a white spectrum. The voltage was controlled through a DC source, as shown in Figure 1a. Twelve measurements were taken of the voltage from the DC source, the voltage across the diode, the current through the circuit, and the intensity. The measurements were taken evenly between 1 to 9 V. The intensity of the diode was evaluated through an glass fibre cable placed directly above the diode. The intensity was displayed in a computer program called AvaSoft, where counts for different wavelengths were shown. The intensity was determined by evaluating the intensity at the largest peak. The integration time used was 70 ms, which involved averaging every 10th measurement.

In the second part, the same circuit was used; however, this time a yellow diode was employed instead. The fibre optic cable was taped directly onto the diode. One measurement was taken of the voltage from the DC source, the voltage across the diode, the current through the circuit, and the intensity. A screenshot was also captured of the spectrum in the AvaSoft program. Keeping the same voltage from the DC source, the diode was placed in liquid nitrogen, and a similar measurement was taken.

In the last part, another circuit was used, as seen in Figure 1b. This time, neither an ammeter nor a voltmeter was used in the main circuit. Instead, a separate circuit was implemented with a diode and a voltmeter connected in parallel. The integration time was changed to 2 ms. The DC source was turned on until the diode in the main circuit shone brightly. The other circuit was then placed close to the main circuit to check if the diode in the smaller circuit registered any voltage. This procedure was repeated for all combinations of red, green, and blue diodes.



(a) This sktch shows the circuit for part 1 and part 2.

(b) This sktch shows the circuit for part 3, with the two different diodes.

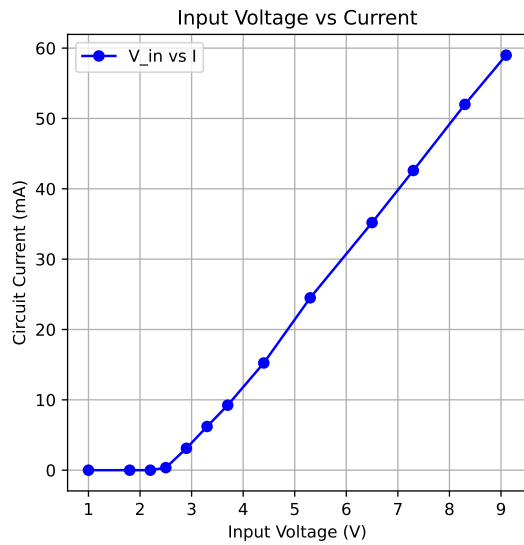
Figure 1: Above one can see the circuits used in this lab. Both circuits used an resistor with  $100\ \Omega$ .

## 4 Result

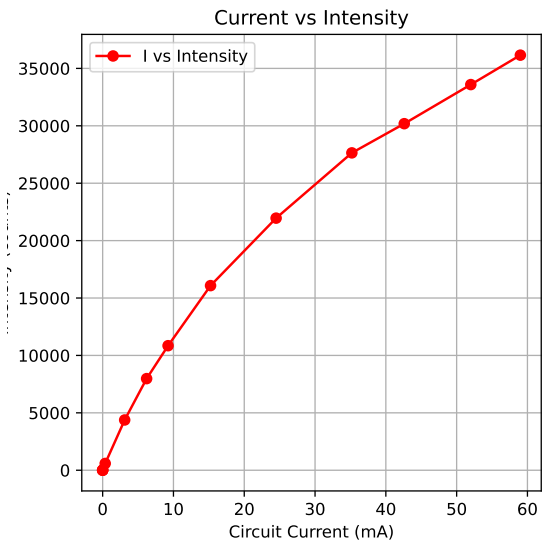
### 4.1 Part 1

In

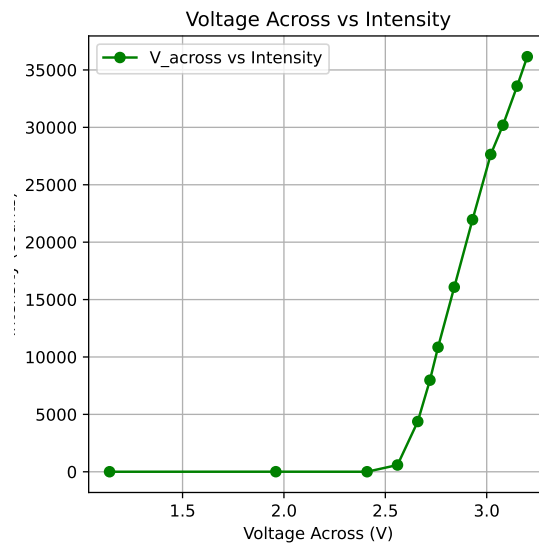
Wavelength white LED: 454.17 nm integration time 70 ms averaging every 10th measurements



(a) Spring



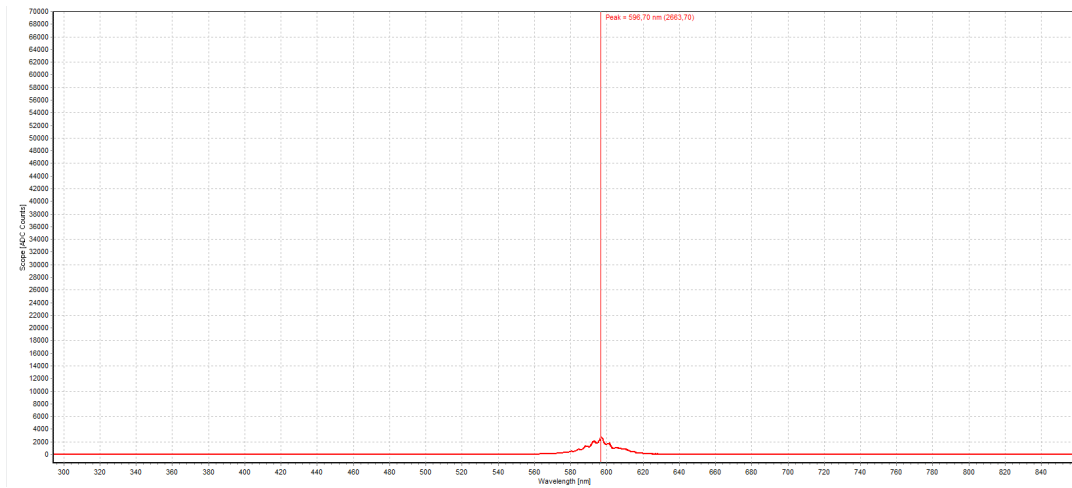
(b) Summer



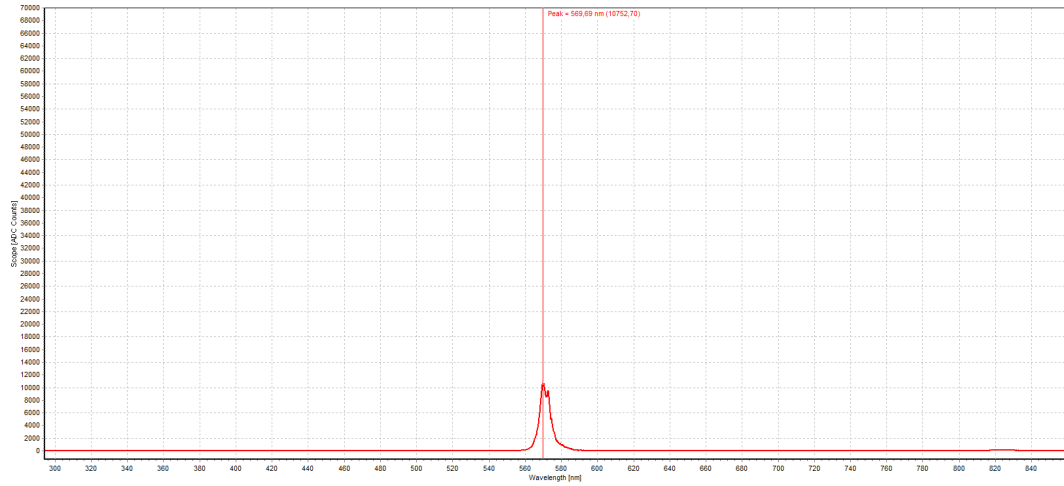
(c) Autumn

Figure 2: Histograms for different seasons.

## 4.2 Part 2



(a) Spring



(b) Summer

Figure 3: ...

Wavelength white LED: 596.85 nm integration time 2 ms averaging every 10th measurements

Before:  $V_{in}$  was 5.0 V,  $V_{across}$  2.06 V,  $I_{circuit}$  30.8 mA and the intensity 2663.70

After:  $V_{in}$  was 5.0 V,  $V_{across}$  4.44 V,  $I_{circuit}$  7.7 mA and the intensity 10752.70

## 4.3 Part 3

Detector/Emitter	Red	Green	Blue
Red	Output	No output	No output
Green	Output	Output	No output
Blue	Output	Output	Output

Table 1: tab:part3

## 5 Discussion

## 6 Conclusion



## References

- [1] Philip Hofmann. *Solid State Physics: An Introduction*. Wiley-VCH, 2nd edition, 2015.